# 🅢 SEMIWILL

## 100A SERIES BI-DIRECTIONAL TRIODE THYRISTOR

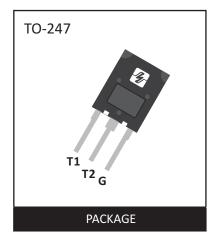
### DESCRIPTION

General purpose switching and phase control applications .These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits such as fan speed and temperature modulation control, lighting control and static switching relay.

#### **FEATURES**

- Repetitive Peak off-State Voltage: 600V/800V/1200V/1600V
- R.M.S On-State Current(IT(RMS)=100A)
- Low on-state voltage: VTM=1.55(Max.)@ ITM
- Low reverse and forward blocking current:
- High Commutation dV/dt.

## T2 OF T1 G SCHEMATIC SYMBOL



## ABSOLUTE MAXIMUM RATINGS (TJ = 25°C UNLESS OTHERWISE SPECIFIED)

Symbol	Parameter	Condition	Ratings	Units
Vdrm	Repetitive Peak Off-State Voltage		600/800/1200/1600	V
Vrrm	Repetitive Peak Reverse Voltage		600/800/1200/1600	V
It(rms)	R.M.S On-State Current	All Conduction Angle	100	А
Ітѕм	Surge OnState Current	F=50Hz, tp=20ms	1000	А
l <sup>2</sup> t	I <sup>2</sup> t for Fusing	tp=10ms	2100	A <sup>2</sup> S
dı/dt	Repetitive rate of rise of on-state current after triggering	Ig=2Ig⊤ F=100Hz tr≤100nS	50	A/uS
Рдм	Forward Peak Gate Power Dissipation		5.0	W
Pg(AV)	Forward Average Gate Power Dissipation		1.0	W
lgм	Peak Gate Current		8.0	А
τ	Operating Junction Temperature		-40~125	°C
Тѕтб	Storage Temperature		-40~150	°C

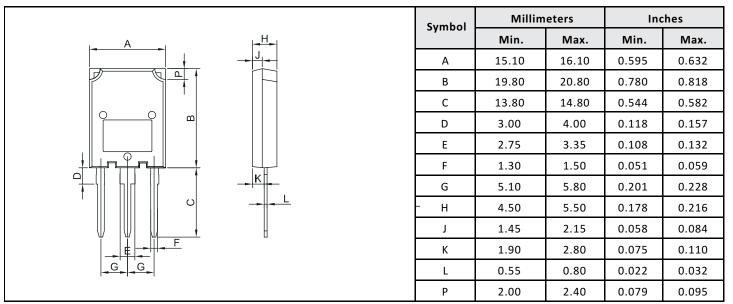
#### BTA100-BTB100

### ELECTRICAL CHARACTERISTICS (TC = 25 °C UNLESS OTHERWISE NOTED)

Symbol	Items	Conditions		Ratings	Unit
I <sub>drm</sub>	Repetitive Peak Off-State Current	Vd = Vdrm	Tc = 25 °C	≤50	uA
			Tc=125 °C	≤10000	
V <sub>TM</sub>	Peak On-State Voltage	Ітм = 120А		≤1.55	V
	Gate Trigger Current	VD= 12V	ΙШШ	≤50	mA
I <sub>GT</sub>			IV	-	
V <sub>GT</sub>	Gate Trigger Voltage	VD=12V		≤1.3	V
V <sub>GD</sub>	Non-Trigger Gate Voltage	V <sub>D</sub> =2/3V <sub>DRM</sub> , T <sub>J</sub> = 125°C		≥0.2	V
dv/dt	Critical Rate of Rise Off-State Voltage	<sub>DRM</sub> , V <sub>D</sub> = 2/3V T <sub>j</sub> = 125°C		≥500	V/uS
I <sub>H</sub>	Holding Current	Ι <sub>τ</sub> =0.1Α		≤80	mA
ΙL	Latching current	IG=1.2IGT	IШ	≤70	mA
			П	≤160	

## PACKAGE MECHANICAL DATA

TO-247



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